Restricted equivalence of paired epsilon {negative and mu{ negative layers to a negative phase {velocity material (alias left {handed material)

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A bstract: The time{harmonic electrom agnetic responses of (a) a bilayer made of an epsilon{negative layer and a mu{negative layer, and (b) a single layer of a negative phase{ velocity material are compared. Provided all layers are electrically thin, a restricted equivalence between (a) and (b) exists. The restricted equivalence depends on the linear polarization state and the transverse wavenum ber. Implications for perfect lenses and parallel{plate waveguides are considered.

K ey words: N egative real perm ittivity, N egative real perm eability, N egative phase velocity, P arallel{plate w aveguide, P erfect lens, P hase velocity, P oynting vector

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1 Introduction

m aterials.

This communication is inspired by the ongoing spate of papers published on the inappropriately designated left-handed materials which are macroscopically homogeneous and display negative phase velocities in relation to the time (averaged Poynting vector, but are not chiral [1]. Nominally, such a material is deemed to possess a relative permittivity scalar $_{\rm r}=_{\rm r}^0+i_{\rm r}^0$ and a relative permeability scalar $_{\rm r}=_{\rm r}^0+i_{\rm r}^0$, both dependent on the angular frequency !, such that both $_{\rm r}^0<0$ and $_{\rm r}^0<0$ in some spectral regime. Originally conceived by Vesselago [3], these materials have been articially realized quite recently [4, 5]. Their fascinating electromagnetic properties can have technological implications of massive proportions [6], but those implications remain speculative at this time. Although these materials have been variously named [1], we prefer the name negative phase (velocity (NPV) materials as the least ambiguous of all extant names.

Using transmission (line analysis and lumped parameters, A lu and Engheta [7] have recently suggested a new route to realizing NPV materials: Take a thin layer of an epsilon (negative (EN) material: it has a negative real permittivity scalar but a positive real permeability scalar. Stick it to a thin layer of a mu (negative (MN)) material, which has a negative real permeability scalar and a positive real permittivity scalar. Provided the two layers are su ciently thin, the paired EN (MN layers could function electively as a NPV material. The clear attraction of this scheme is that EN and MN layers are easier to manufacture, very likely, than the NPV materials fabricated thus far [4, 5].

O ur objective here is to exam ine the suggested scheme using continuum—eld theory, and to establish a restricted equivalence of an EN {M N bilayer to a NPV m aterial. Implications 2 The condition for the phase velocity and the time {averaged Poynting vector to be oppositely directed is $(j_r j \ ^0_r) (j_r j \ ^0_r) > ^0_r ^0_r$, which permits | more generally | 0_r and/or 0_r to be negative [2]. An exp(i!t) time {dependence having been assumed here, $^0_r > 0$ and $^0_r > 0$ at all! > 0 for all passive

for parallel(plate waveguides [7] and perfect lenses [8] are deduced therefrom.

A note about notation: Vectors are in boldface, column vectors are boldface and enclosed in square brackets, while matrixes are denoted by G othic letters; $_0$ and $_0$ are the free{space perm ittivity and perm eability, respectively; and k_0 = $~!~(_0~_0)^{1=2}~$ is the free{ space wavenum ber. A cartesian coordinate system is used, with u_x , u_y and u_z as the unit vectors.

Bilayer Theory in Brief

C onsider the layers $0 < z < d_a$ and $d_a < z < d_a + d_b$. Their constitutive relations are as follows:

D (r) =
$${}_{0} a E (r) \stackrel{9}{\geq}$$

B (r) = ${}_{0} a H (r) \stackrel{?}{,}$; 0 < z < d_{a} ; (1)
D (r) = ${}_{0} b E (r) \stackrel{2}{\geq}$
B (r) = ${}_{0} b H (r) \stackrel{?}{,}$; $d_{a} < z < d_{a} + d_{b}$: (2)

D (r) =
$${}_{0} {}_{b}E$$
 (r) $\stackrel{9}{\geq}$; $d_{a} < z < d_{a} + d_{b}$: (2) B (r) = ${}_{0} {}_{b}H$ (r) $\stackrel{7}{\downarrow}$

The constitutive parameters present in the foregoing equations are complex (valued with positive imaginary parts (as be ts any passive medium). The two half(spaces on either sides of the bilayer are vacuous.

W ithout loss of generality, the electrom agnetic eld phasors everywhere can be written as [9]

E (r) =
$$e(z)e^{i \times \frac{9}{2}}$$
; 1 < z < 1; (3)

where the transverse wavenumber 2 [0; 1). The elds inside the bilayer must follow the 4 4 m atrix ordinary di erential equation [9, 10]

$$\frac{d}{dz}$$
 [f(z)] = iP(z) [f(z)]; 0 < z < d_a + d_b: (4)

In this equation, $[f(z)] = \infty l$ $e_x(z)$; $e_y(z)$; $h_x(z)$; $h_y(z)$ is a column vector, while the 4 4 m atrix function P(z) is piecew ise uniform as

$$P(z) = \begin{cases} 8 \\ P_{a}; & 0 < z < d_{a} \\ P_{b}; & d_{a} < z < d_{a} + d_{b} \end{cases}$$
(5)

w here

$$P_{a,b} = \begin{cases} 2 & 0 & 0 & 0 & \frac{2}{! \cdot 0 \cdot a,b} + ! \cdot 0 \cdot a,b \cdot \frac{7}{7} \\ 0 & 0 & ! \cdot 0 \cdot a,b \cdot \frac{2}{! \cdot 0 \cdot a,b} & 0 & 0 & \frac{7}{7} \end{cases}$$

$$! \cdot 0 \cdot a,b \cdot 0 & 0 & 0 & 0 \end{cases}$$

The only nonzero elements of the matrixes $P_{a,b}$ appear on their antidiagonals, of which the (2;3) and the (3;2) elements are relevant to s{polarized elds, and the (1;4) and the (4;1) elements to the p{polarized elds.

The solution of (4) is straightforward, because the matrix P (z) is piecewise uniform [12]. Thus, the algebraic relation

$$[f(d_b + d_a)] = e^{iP_b d_b} e^{iP_a d_a} [f(0)]$$
 (7)

is su cient to solve both re ection/transm ission problems as well as guided {wave propagation problems. The two matrix exponentials on the right side of (7) cannot be interchanged | unless the matrixes P_a and P_b also commute, which is possible with dissimilar materials only in quite special circum stances [10, 11].

3 Analysis

M atrixes $P_{a,b}$ have $\begin{pmatrix} q & & & \\ k_0^2 & a,b & a,b \end{pmatrix} = \begin{pmatrix} a_{a,b} & a_{a,b} & b \\ a_{a,b} & a_{a,b} & a_{a,b} \end{pmatrix}$ as their eigenvalues. P rovided that $j_{a,b} j d_{a,b}$ 1 (i.e., both layers are electrically thin), the approximations

$$e^{iP_{a,b}d_{a,b}} \cdot I + iP_{a,b}d_{a,b}$$
 (8)

can be made, with I as the 4 4 identity matrix. Then

$$e^{iP_{b}d_{b}}e^{iP_{a}d_{a}}$$
, $I + iP_{a}d_{a} + iP_{b}d_{b}$, $e^{iP_{a}d_{a}}e^{iP_{b}d_{b}}$; (9)

and the two layers in the bilayer can be interchanged without signi cant e ect [13].

Let us now consider a single layer of relative perm ittivity $_{\rm eq}$, relative perm eability $_{\rm eq}$ and thickness $d_{\rm eq}$. Quantities $P_{\rm eq}$ and $_{\rm eq}$ can be de ned in analogy to $P_{\rm a}$ and $_{\rm a}$. Two thickness ratios are de ned as

$$p_{a,b} = \frac{d_{a,b}}{d_{eq}} \qquad 0;$$
 (10)

in order to compare the single layer with the previously described bilayer. There is no hidden restriction on the non{negative real numbers p_a and p_b .

Provided that $j_{eq}jd_{eq}$ 1 (i.e., the single layer is electrically thin as well), the approximation

$$e^{iP_{eq}d_{eq}}$$
 / I + $iP_{eq}d_{eq}$ (11)

can be made. Equations (9) and (11) perm it us to establish the following equivalences between a bilayer and a single layer:

(i) s{polarization: The only nonzero eld components are E_y , H_x and H_z . Therefore, the equality of the (2;3) elements of $p_a P_a + p_b P_b$ and P_{eq} , and likewise of the (3;2) elements, has to be guaranteed for equivalence; thus, the equations

$$p_{a \ a} + p_{b \ b} = e_{eq};$$
 (12)

$$p_{a a} + p_{b b}$$
 $\frac{2}{k_0} \frac{p_a}{a} + \frac{p_b}{b} = eq \frac{2}{k_0} \frac{1}{eq}$ (13)

have to solved for $_{eq}$ and $_{eq}$. We conclude therefrom that, for a given value of and subject to the thickness restrictions j $_{a,b,eq}$ jd $_{a,b,eq}$ $^{<}$ 0:1, the bilayer and a single layer are equivalent with respect to the transform ation of the x { and y { components of the elds from one exterior face to the other exterior face if

$$_{eq} = p_{a a} + p_{b b}$$

$$\frac{1}{k_0} = \frac{1}{k_0} \frac{p_a p_b (a b)^2}{a b (p_a a + p_b b)} + \frac{(p_a + p_b + 1) (p_a + p_b 1)}{p_a a + p_b b};$$
(14)

(ii) p{polarization: The only nonzero eld components being H_y , E_x and E_z , the equality of the (1;4) elements of $p_a P_a + p_b P_b$ and P_{eq} su ces, along with the equality of the (4;1) elements of the two matrixes. For a given value of and subject to the thickness restrictions j_{a,b,eq}jd_{a,b,eq} < 0:1, the bilayer and a single layer are equivalent if

$$eq = p_{a a} + p_{b_{m}b}$$

$$= \frac{2}{k_{0}} \frac{p_{a}p_{b}(a b)^{2}}{ab(p_{a a} + p_{b b})} + \frac{(p_{a} + p_{b} + 1)(p_{a} + p_{b} 1)}{p_{a a} + p_{b b}};$$
(16)

C learly, the constitutive param eters of the equivalent layer are functions of both p_a and p_b ; and we must point out that the sum of these two ratios need not equal unity. Furtherm ore, except for normal incidence (i.e., = 0), the constitutive param eters of the equivalent layer depend on the incident linear polarization state. Finally, the constitutive param eters of the equivalent layer change with the transverse wavenumber .

The foregoing equations can be manipulated to yield negative values of both $_{\rm eq}^0$ and $_{\rm eq}^0$ for either

an EN {M N bilayer
$$f_a^0 < 0$$
; $_b^0 > 0$; $_a^0 > 0$; $_b^0 < 0$ g or a M N {EN bilayer $f_a^0 > 0$; $_b^0 < 0$; $_a^0 < 0$; $_a^0 > 0$ g.

An EN $\{M \ N \ bilayer is equivalent to a NPV \ layer for both polarization states when = 0, provided the condition$

$$\frac{\dot{j}_{b}^{0}\dot{j}}{\frac{0}{a}} > \frac{p_{a}}{p_{b}} > \frac{\frac{0}{b}}{\dot{j}_{a}^{0}\dot{j}}$$
 (18)

holds true. The inequality (18) is applicable for a M N (EN bilayer also, if the subscripts a

and b are interchanged therein, i.e.,

$$\frac{\dot{j}_{a}^{0}\dot{j}}{\dot{p}_{b}} > \frac{p_{b}}{p_{a}} > \frac{\dot{a}}{\dot{j}_{b}^{0}\dot{j}}; \tag{19}$$

A further specialization of $p_a + p_b = 1$ leads to the inequality

$$\frac{\dot{j}_{b}^{0}\dot{j}}{a^{0} + \dot{j}_{b}^{0}\dot{j}} > p_{a} > \frac{\dot{0}}{\dot{j}_{a}^{0}\dot{j} + \dot{0}}$$
(20)

for EN {M N bilayers, and

$$\frac{j_{a}^{0}j}{p+j_{a}^{0}j} > p_{b} > \frac{0}{j_{b}^{0}j+0}$$
(21)

for M N (EN bilayers.

The inequalities (18){ (21) should be adequate for both s{ and p{polarization states when $=k_0$ 1. In general, however, a given EN {M N (or M N {EN) bilayer is equivalent to a di erent NPV m aterial for a di erent linear polarization state and/or transverse wavenum ber. Thus, the equivalence between an EN {M N (or a M N {EN) bilayer and a NPV layer is restricted.

The restricted equivalence has an interesting in plication for perfect lenses [8]. A perfect lens of thickness d > 0 is defined by the full liment of the condition [f(d)] = [f(0)] for all! and . Because of dispersion and dissipation, at best, this condition is fullled approximately. Let us imagine that the condition is fullled by some NPV constitutive parameters for some! and all j j ^. Then, the implementation of the acceptably imperfect lens as a cascade of thin EN-MN (or MN {EN}) bilayers would require that the successive bilayers have different constitutive parameters and that the entry as well as the exit faces be curved, and even those steps may not suce. In contrast, is xed for any single (mode parallel (plate waveguide, and so is the range of operating frequencies; and the emulation of a NPV material via EN (MN) (or MN {EN}) bilayers may not be onerous.

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